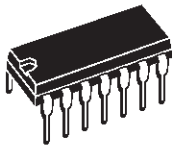
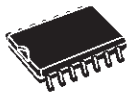
74ACT280

9 BIT PARITY GENERATOR/CHECKER

- HIGH SPEED: t_{PD} = 4 ns (TYP.) at V_{CC} = 5V
- LOW POWER DISSIPATION: I_{CC} = 4 µA (MAX.) at T_A = 25 °C
- COMPATIBLE WITH TTL OUTPUTS V_{IH} = 2V (MIN), V_{IL} = 0.8V (MAX)
- 50Ω TRANSMISSION LINE DRIVING CAPABILITY
- SYMMETRICAL OUTPUT IMPEDANCE: $|I_{OH}| = I_{OL}$ = 24 mA (MIN)
- BALANCED PROPAGATION DELAYS: $t_{PLH} \cong t_{PHL}$
- OPERATING VOLTAGE RANGE: V_{CC} (OPR) = 4.5V to 5.5V
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 280
- IMPROVED LATCH-UP IMMUNITY



B
(Plastic Package)



M
(Micro Package)

ORDER CODES :

74ACT280B 74ACT280M

DESCRIPTION

The AC280 is an advanced high-speed CMOS 9 BIT PARITY GENERATOR - CHECKER fabricated with sub-micron silicon gate and double-layer metal wiring C^2MOS technology. It is ideal for low power applications mantaining high speed operation similar to eqivalent Bipolar Schottky TTL.

It is composed of nine data inputs (A to I) and odd/even parity outputs (ΣODD and ΣEVEN). The nine data inputs control the output conditions. When the number of high level input is odd, ΣODD output is kept high and ΣEVEN output low. Conservely, when the output is even, ΣEVEN output is kept high and ΣODD low.

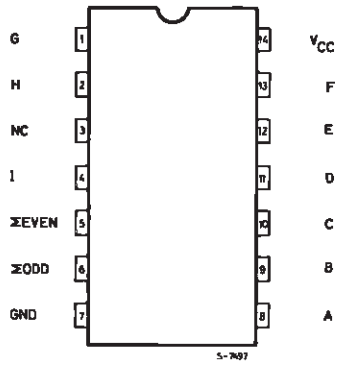
The IC generates either odd or even parity making it flexible application.

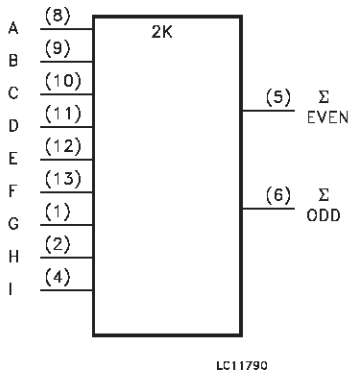
The word-length capability is easily expanded by cascading.

The device is designed to interface directly High Speed CMOS systems with TTL, NMOS and CMOS output voltage levels.

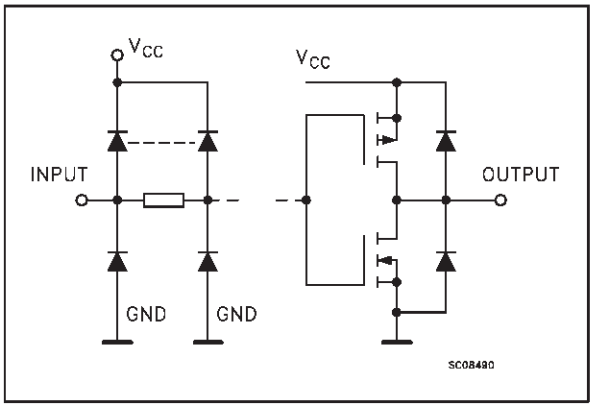
All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

PIN CONNECTION AND IEC LOGIC SYMBOLS





INPUT AND OUTPUT EQUIVALENT CIRCUIT



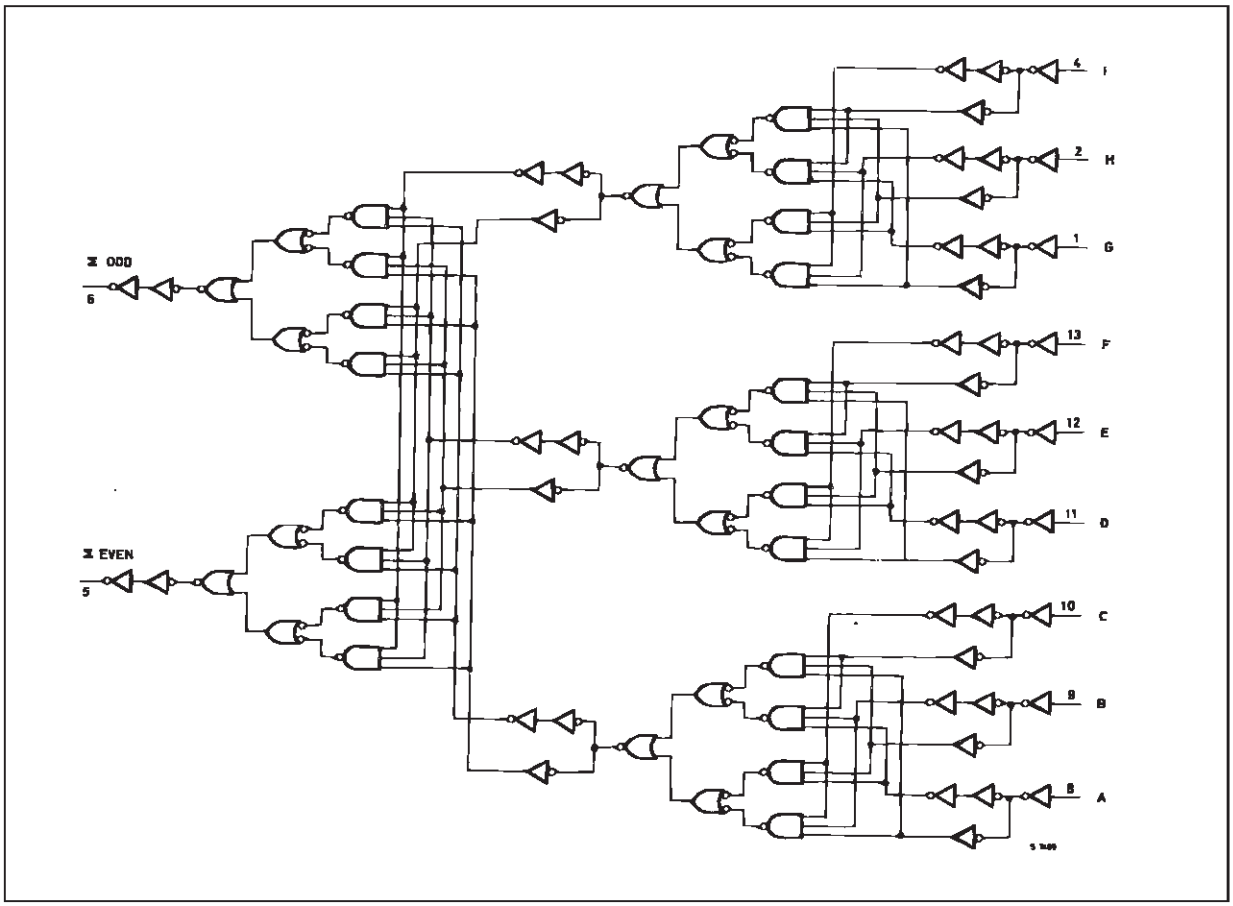
PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
5, 6	ΣEVEN ΣODD	Parity Outputs
8, 9, 10, 11, 12, 13, 1, 2, 4	A to I	Data Inputs
3	NC	No Connection
7	GND	Ground (0V)
14	V_{CC}	Positive Supply Voltage

TRUTH TABLE

NUMBER OF INPUT A TRHU I THAT ARE HIGH	OUTPUT	
	ΣEVEN	ΣODD
0, 2, 4, 6, 8	H	L
1, 3, 5, 7, 9	L	H

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7	V
V_I	DC Input Voltage	-0.5 to V_{CC} + 0.5	V
V_O	DC Output Voltage	-0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Current	± 50	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 200	mA
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	4.5 to 5.5	V
V_I	Input Voltage	0 to V_{CC}	V
V_O	Output Voltage	0 to V_{CC}	V
T_{op}	Operating Temperature:	-40 to +85	°C
dt/dv	Input Rise and Fall Time V_{CC} = 4.5 to 5.5V (note 1)	8	ns/V

1) V_{IN} from 0.8 V to 2.0 V

DC SPECIFICATIONS

Symbol	Parameter	Test Conditions			Value					Unit
		Vcc (V)			T_A = 25 °C			-40 to 85 °C		
					Min.	Typ.	Max.	Min.	Max.	
V_{IH}	High Level Input Voltage	4.5	V_O = 0.1 V or V_{CC} - 0.1 V		2.0	1.5		2.0		V
		5.5			2.0	1.5		2.0		
V_{IL}	Low Level Input Voltage	4.5	V_O = 0.1 V or V_{CC} - 0.1 V			1.5	0.8		0.8	V
		5.5				1.5	0.8		0.8	
V_{OH}	High Level Output Voltage	4.5	V_I(*) = V_{IH} or V_{IL}	I_O=-50 µA	4.4	4.49		4.4		V
		5.5		I_O=-50 µA	5.4	5.49		5.4		
		4.5		I_O=-24 mA	3.86			3.76		
		5.5		I_O=-24 mA	4.86			4.76		
V_{OL}	Low Level Output Voltage	4.5	V_I(*) = V_{IH} or V_{IL}	I_O=50 µA		0.001	0.1		0.1	V
		5.5		I_O=50 mA		0.001	0.1		0.1	
		4.5		I_O=24 mA			0.36		0.44	
		5.5		I_O=24 mA			0.36		0.44	
I_I	Input Leakage Current	5.5	V_I = V_{CC} or GND				±0.1		±1	µA
I_{CCT}	Max I_{CC} /Input	5.5	V_I = V_{CC} -2.1 V			0.6			1.5	mA
I_{CC}	Quiescent Supply Current	5.5	V_I = V_{CC} or GND				4		40	µA
I_{OLD}	Dynamic Output Current (note 1, 2)	5.5	V_{OLD} = 1.65 V max						75	mA
I_{OHD}			V_{OHD} = 3.85 V min						-75	mA

1) Maximum test duration 2ms, one output loaded at time

2) Incident wave switching is guaranteed on transmission lines with impedances as low as 50 Ω.

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, R_L = 500 Ω, Input $t_r = t_f$ =3 ns)

Symbol	Parameter	Test Condition		Value					Unit
		V_{CC} (V)		T_A = 25 °C			-40 to 85 °C		
				Min.	Typ.	Max.	Min.	Max.	
t_{PLH} t_{PHL}	Propagation Delay Time (Input - ΣODD, ΣEVEN)	5.0(*)		3.0	8.5	13.0	2.0	14.5	ns

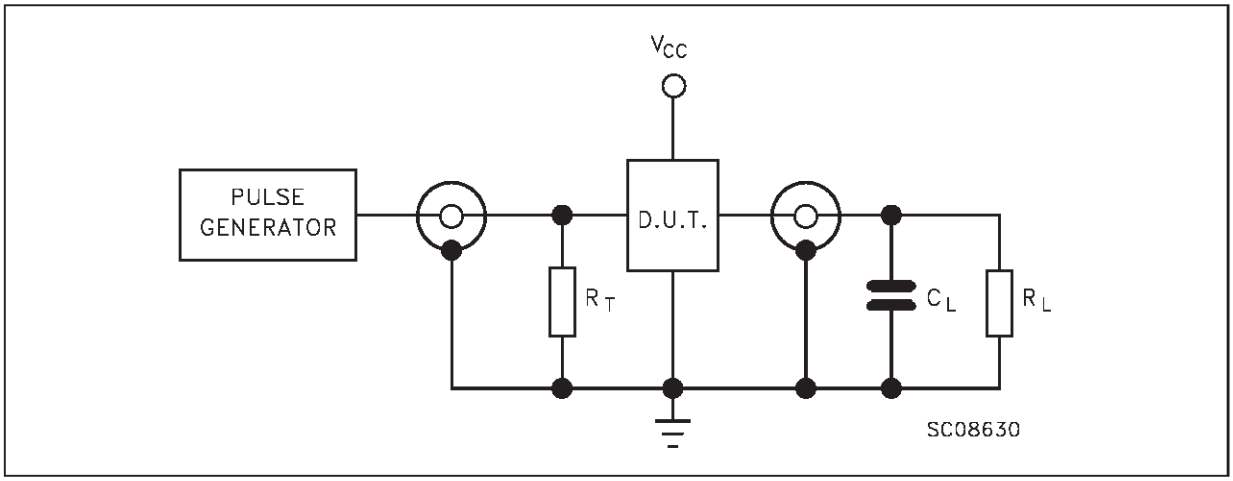
(*) Voltage range is 5V ± 0.5V

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions		Value					Unit
		V_{CC} (V)		T_A = 25 °C			-40 to 85 °C		
				Min.	Typ.	Max.	Min.	Max.	
C_{IN}	Input Capacitance	5.0			4				pF
C_{PD}	Power Dissipation Capacitance (note 1)	5.0			75				pF

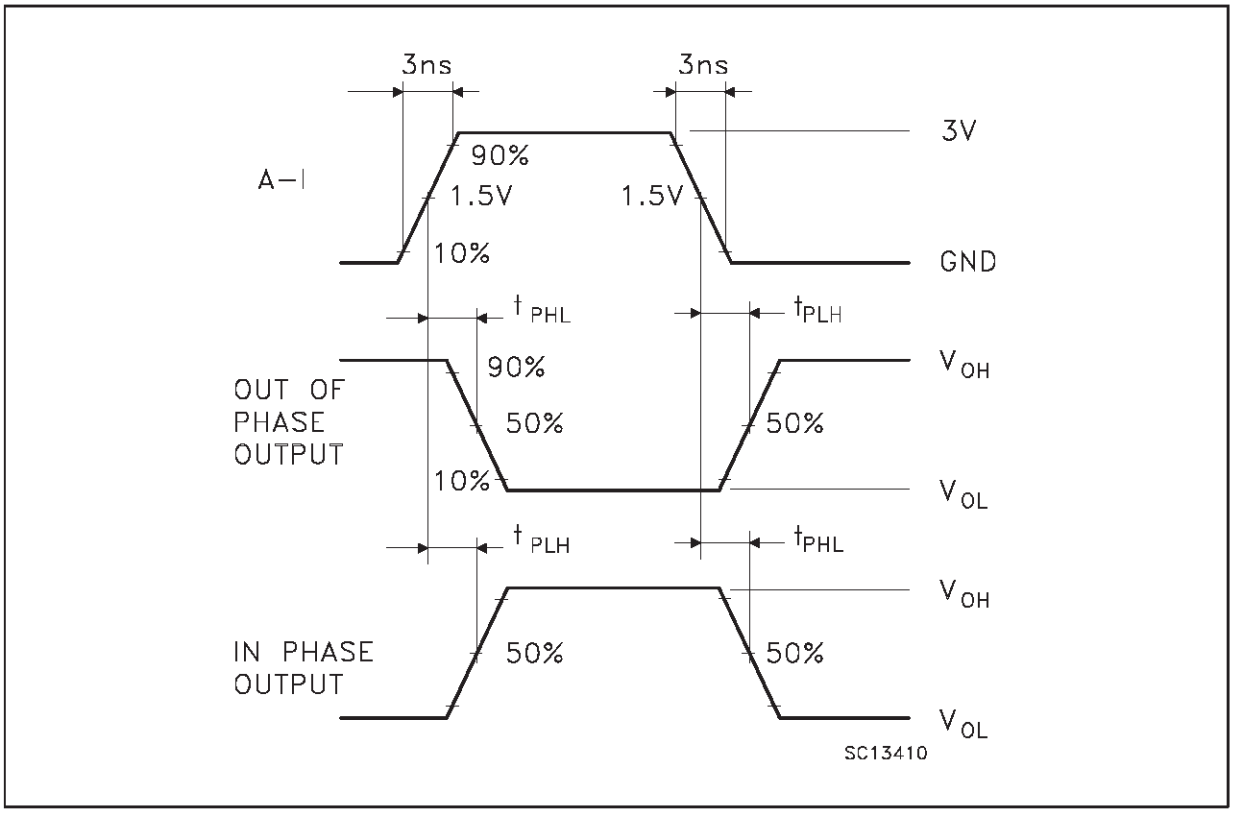
1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC}(opr) = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}$

TEST CIRCUIT



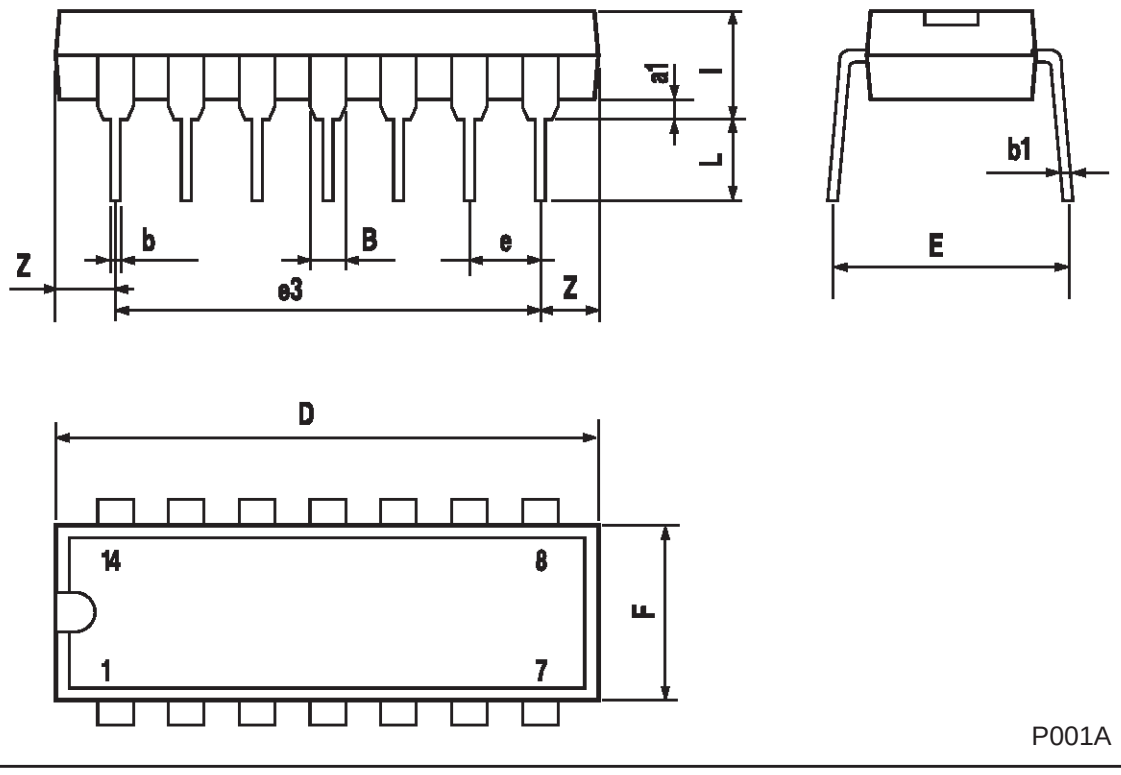
C_L = 50 pF or equivalent (includes jig and probe capacitance)
$R_L = R_1$ = 500Ω or equivalent
$R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

WAVEFORM: PROPAGATION DELAYS (f=1MHz; 50% duty cycle)



Plastic DIP-14 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100



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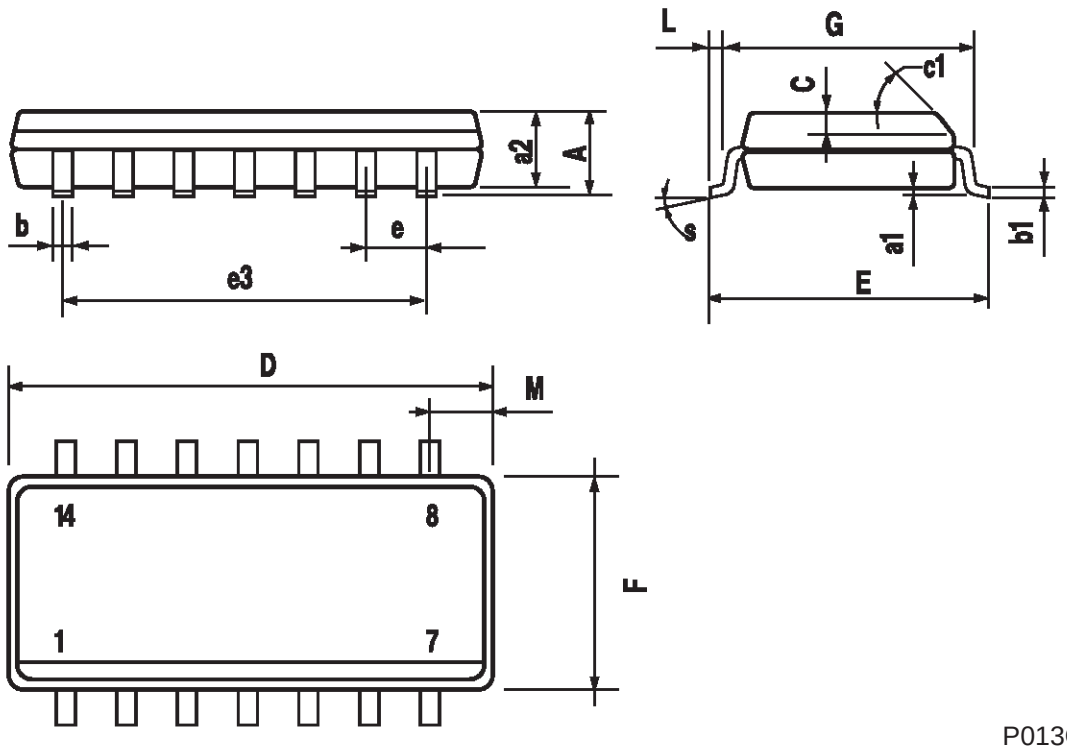
SO-14 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45 (typ.)					
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S	8 (max.)					



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